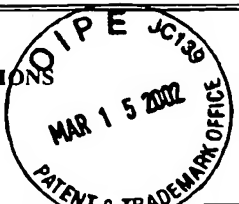


<b>Form PTO-1449 (Modified)</b>  <b>LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT</b> (Use several sheets if necessary)		Atty. Docket No. 71493-1041	Serial No. 10/025,866
		Applicant John White	
		Filing Date December 26, 2001	Group 2881




**REFERENCE DESIGNATION U.S. PATENT DOCUMENTS**

EXAM. INIT.	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FIL. DATE IF APPROPRIATE
AA						

**FOREIGN PATENT DOCUMENTS**

	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB CLASS	TRANSLATION	
						YES	NO
AB							

**OTHER ART (including Author, Title, Date, Pertinent Pages, Etc.)**

	AC		Zah Chung-En et al: "High-Performance Uncooled 1.3µm Al <sub>0.15</sub> Ga <sub>0.85</sub> As/InP Strained-Layer Quantum-Well Lasers for Subscriber Loop Applications", IEEE Journal of Quantum Electronics, February 1994, vol. 30, no. 2, pages 511-523
	AD		Lowery Arthur J. et al: "Performance Comparison of Gain-Coupled and Index-Coupled DFB Semiconductor Lasers", IEEE Journal of Quantum Electronics, September 1994, vol. 30, no. 9, pages 2051-2063
	AE		Lu Hanh et al: "Dynamic Properties of Partly Gain-Coupled 1.55-µm DFB Lasers", IEEE Journal of Quantum Electronics, August 1995, vol. 31, no. 8, pages 1443-1450
	AF		Lu Hanh et al: "Single-Mode Operation Over a Wide Temperature Range in 1.3µm InGaAsP/InP Distributed Feedback Lasers", Journal of Lightwave Technology, May 1996, vol. 14, no. 5, pages 851-859
	AG		Chen Jianyao et al: "Transient Side-Mode Suppression in Gain-Coupled DFB Lasers", IEEE Journal of Quantum Electronics, January 1998, vol. 34, no. 1, pages 113-119
	AH		Hong J. et al: "Strongly Gain-Coupled (SGC) Coolerless (-40°C ~ +85°C) MQW DFB Lasers", IEEE Journal of Selected Topics in Quantum Electronics, May/June 1999, vol. 5, no. 3, pages 442-448
	AI		Massara A.B. et al: "Ridge waveguide InGaAsP lasers with uncooled 10Gbit/s operation at 70°C", Electronics Letters, September 16, 1999, vol. 35, no. 19, pages 1646-1647
	AJ		Champagne A. et al: "Global and Local Effects in Gain-Coupled Multiple-Quantum-Well DFB Lasers". IEEE Journal of Quantum Electronics, October 1999, vol. 35, no. 10, pages 1390-1401
	AK		Springthorpe A.J. et al: "Strained 1.3µm MQW AlGaInAs lasers grown by digital alloy MBE", Electronics Letters, June 8, 2000, vol. 36, no. 12, pages 1031-1032
	AL		Ebberg A. et al: "10 Gbit/s transmission using directly modulated uncooled MQW ridge waveguide DFB lasers in TO package", Electronics Letters, August 17, 2000, vol. 36, no. 17, pages 1476-1477
	AM		White J.K. et al: "85°C Investigation of Uncooled 10-Gb/s Directly Modulated InGaAsP RWG GC-DFB Lasers", IEEE Photonics Technology Letters, August 2001, vol. 13, no. 8, pages 773-775
	AN		Yang S. et al: "Enhanced Performance of Uncooled Strongly-Gain-Coupled MQW DFB Lasers in 10Gb/s Link Applications", paper presented at European Conference for Optical Communications, Fall 2001
EXAMINER 			DATE CONSIDERED 3/12/04

EXAMINER:

Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.